

L Number	Hits	Search Text	DB	Time stamp
1	12947	TEOS	USPAT; US-PGPUB; JPO	2003/03/19 18:44
2	1357	LPCVD same TEOS	USPAT; US-PGPUB; JPO	2003/03/19 18:44
3	4350	spacer\$1 with (silicon adj nitride or ("si.sub3 n.sub.4"))	USPAT; US-PGPUB; JPO	2003/03/19 18:45
4	290413	etch\$3	USPAT; US-PGPUB; JPO	2003/03/19 18:45
5	617	(LPCVD same TEOS) same etch\$3	USPAT; US-PGPUB; JPO	2003/03/19 18:45
6	159	(spacer\$1 with (silicon adj nitride or ("si.sub3 n.sub.4")))) and ((LPCVD same TEOS) same etch\$3)	USPAT; US-PGPUB; JPO	2003/03/19 18:56
7	43585	etch\$3 with (recess\$2 or groove\$1 or trench\$2 or concave\$1)	USPAT; US-PGPUB; JPO	2003/03/19 18:57
8	523399	gate\$1	USPAT; US-PGPUB; JPO	2003/03/19 18:57
9	126438	implant\$3	USPAT; US-PGPUB; JPO	2003/03/19 18:57
10	7541	(ldd or (lightly adj doped adj drain) or extension) same implant\$3	USPAT; US-PGPUB; JPO	2003/03/19 18:58
11	219599	spacer\$1	USPAT; US-PGPUB; JPO	2003/03/19 18:58
12	927	((ldd or (lightly adj doped adj drain) or extension) same implant\$3) and spacer\$1 and (etch\$3 with (recess\$2 or groove\$1 or trench\$2 or concave\$1)) and gate\$1	USPAT; US-PGPUB; JPO	2003/03/19 18:58
13	11176	isotropi\$5 near10 etch\$3	USPAT; US-PGPUB; JPO	2003/03/19 18:59
14	200	((((ldd or (lightly adj doped adj drain) or extension) same implant\$3) and spacer\$1 and (etch\$3 with (recess\$2 or groove\$1 or trench\$2 or concave\$1)) and gate\$1) and (isotropi\$5 near10 etch\$3))	USPAT; US-PGPUB; JPO	2003/03/19 18:59
15	727	((((ldd or (lightly adj doped adj drain) or extension) same implant\$3) and spacer\$1 and (etch\$3 with (recess\$2 or groove\$1 or trench\$2 or concave\$1)) and gate\$1) not (((ldd or (lightly adj doped adj drain) or extension) same implant\$3) and spacer\$1 and (etch\$3 with (recess\$2 or groove\$1 or trench\$2 or concave\$1)) and gate\$1) and (isotropi\$5 near10 etch\$3))	USPAT; US-PGPUB; JPO	2003/03/19 18:59